

Serial Nr.: 10/699,490  
Art Unit: 2856

03222-URS

AMENDMENTS TO THE ABSTRACT:

The present invention relates to A silicon dual inertial sensor sensors made of a (110) silicon chip. The invention chip comprises at least [[an]] a proof-mass, which is connected to [[an]] a corresponding inner frame with a plurality of sensing resilient beams to make it easier for [[said]] the proof-mass to move perpendicular to the surface of [[said]] the silicon chip (defined as z-axis), and each inner frame is connected to [[the]] an outer frame with a plurality of driving resilient beams, or connected to [[the]] common connection beam beams, which [[is]] are then connected to a central anchor with [[the]] common resilient supporting beams beam to make it easier for [[said]] the inner frame to move in parallel with the surface of [[said]] the silicon chip (defined as y-axis). Each inner frame is driven by a driver to move in an opposite direction along the y-axis, and also move the proof-mass in the opposite direction along the y-axis, if y-axis. If there is a rotation rate input along the x-axis, it will generate generates a Coriolis force to make each [[said]] proof-mass [[to]] move in the opposite direction of the z-axis, if z-axis. If an acceleration is input along the z-axis, the specific force will move the [[said]] proof-masses with the same direction; when said proof-mass dirccction. When the proof-masses move or oscillate, the capacitance of the capacitor formed with sensing electrodes will change due to the change of distance; hence the of the distance. The moving distance can be obtained by measuring the change of capacitance; as the capacitance. Because the rotation rate outputs an alternating signal, and the acceleration outputs a direct signal, they can be separated with signal processing. The present invention utilizes the deep vertical etching characteristics of the (110) silicon chip is utilized to make the driving

Serial Nr.: 10/699,490  
Art Unit: 2856

03222-URS

beam in order to control the driving resonance frequency more precisely, and improve improves the yield rate and the performance of the gyroscope.